









	<b>MBR60030CT</b>	
	<b>Hersteller-Teilenummer:</b>	MBR60030CT
	<b>Hersteller / Marke:</b>	GeneSiC Semiconductor
	<b>Teil der Beschreibung:</b>	DIODE MODULE 30V 300A 2TOWER
	<b>Datenblätter:</b>	<a href="#">1.MBR60030CT.pdf</a> <a href="#">2.MBR60030CT.pdf</a>
	<b>RoHS Status:</b>	Bleifrei / RoHS-konform
<p>Image may be representation. See specs for product details.</p>	<b>Lagerzustand:</b>	New original, 3000 pcs Stock Available.
	<b>Liefern von:</b>	Hong Kong
	<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS

Spezifikationen

Teilenummer	MBR60030CT
Hersteller	GeneSiC Semiconductor
Beschreibung	DIODE MODULE 30V 300A 2TOWER
Kategorie	Diskrete Halbleiterprodukte > Dioden-Gleichrichter-
Teilstatus	3000 pcs Stock
Serie	-
Befestigungsart	Chassis Mount
Verpackung / Gehäuse	Twin Tower
Supplier Device-Gehäuse	Twin Tower
Diodentyp	Schottky
Spannung - Forward (Vf) (Max) @ If	750mV @ 300A
Strom - Sperrleckstrom @ Vr	1mA @ 20V
Diodenkonfiguration	1 Pair Common Cathode
Spannung - Sperr (Vr) (max)	30V
Strom - Richt (Io) (pro Diode)	300A
Geschwindigkeit	Fast Recovery = 200mA (Io)
Verpackung	Bulk

MBR60030CT ist neu im Original, Suche MBR60030CT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie MBR60030CT GeneSiC Semiconductor mit Garantie und Vertrauen. Anfrage MBR60030CT: Info@Y-IC.com

Sie können auch interessiert sein:

 <p><b>MBR60020CT</b> GeneSiC Semiconductor DIODE MODULE 20V 300A 2TOWER</p>	 <p><b>MBR60030CTRL</b> GeneSiC Semiconductor DIODE SCHOTTKY 30V 300A 2 TOWER</p>	 <p><b>MBR60020CTR</b> GeneSiC Semiconductor DIODE MODULE 20V 300A 2TOWER</p>	 <p><b>MBR60030CTR</b> GeneSiC Semiconductor DIODE MODULE 30V 300A 2TOWER</p>
 <p><b>MBR60020CTRL</b> GeneSiC Semiconductor DIODE SCHOTTKY 20V 300A 2 TOWER</p>	 <p><b>MBR60035</b> MOTOROLA IGBT Modules</p>	 <p><b>MBR60030CTL</b> GeneSiC Semiconductor DIODE SCHOTTKY 30V 300A 2 TOWER</p>	 <p><b>MBR60020CTL</b> GeneSiC Semiconductor DIODE SCHOTTKY 20V 300A 2 TOWER</p>

heiße Teile

Mehr

- |                    |                    |                    |                    |                    |
|--------------------|--------------------|--------------------|--------------------|--------------------|
| ⊗ MBR4050PT        | ↔ MBR4050PT        | ⇒ MBR4060CT        | D MBR4060PT        | ⇒ MBR4060PT        |
| ⊣ MBR4060PT        | ⊗ MBR4060WTPBF     | D MBR4080PT        | ⇒ MBR40H45CT       | ⇒ MBR40H45CT-E3/45 |
| ⊗ MBR40H45CT-E3/45 | ⊣ MBR40H50CT-E3/45 | ⊗ MBR40H50CT-E3/45 | ↔ MBR40H60CT-E3/45 | ⇒ MBR40H60CT-E3/45 |
| D MBR40L15CWPBF    | ⊗ MBR41H100CT-1G   | ⊣ MBR41H100CTG     | ⊗ MBR50XPA120-50   | ⇒ MBR540RLG        |
| ⇒ MBR540VSTR-G1    | ↔ MBR540VSTR-G1    | ⊗ MBR5H150VPTR-E1  | ⊣ MBR600100CT      | ⇒ MBR60020CT       |
| ↔ MBR60035         | ⇒ MBR60035CT       | D MBR60035CTL      | ⊗ MBR60040         | ⊣ MBR60040CT       |
| ⊗ MBR60045CT       | D MBR60100CT       | ⇒ MBR60100PT       | ↔ MBR60200PT       | ⇒ MBR6030PT        |
| ⊣ MBR6040PT        | ⊗ MBR6045PT        | ↔ MBR6045PT        | ⇒ MBR6045WTPBF     | ⇒ MBR6060PT        |
| ⊗ MBR760CT         | ⊣ MBRA120ET3       | ⊗ MBRA120ET3G      | D MBRA120ET3G      | ⇒ MBRA120LT3G      |
| ↔ MBRA120T3G       | ⊗ MBRA120TR        | ⊣ MBRA120TRPBF     | ⊗ MBRA130LT3       | ⇒ MBRA130LT3G      |

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